

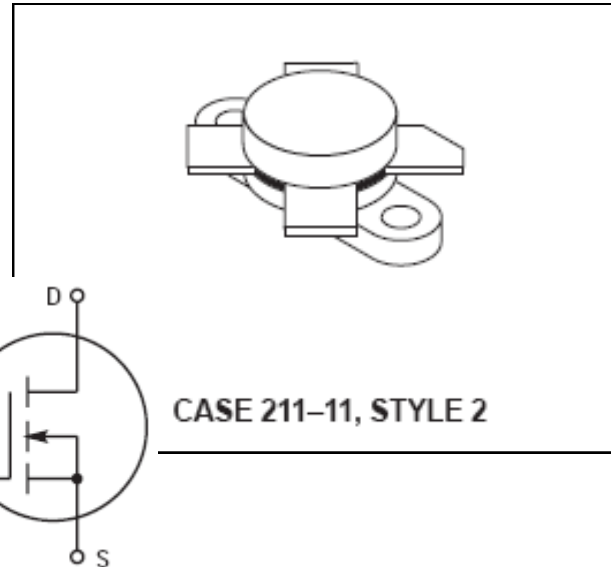
## RF Power FET 150W, to 175MHz, 28V

Rev. V1

Designed for broadband commercial and military applications at frequencies to 175 MHz. The high power, high gain and broadband performance of this device is especially useful for FM broadcast or TV channel frequency band solid state transmitters and amplifiers.

- Guaranteed performance at 30 MHz, 28V:  
Output power: 150W  
Gain: 8dB (22dB Typ.)  
Efficiency: 40%
- Typical Performance at 175MHz, 50V:  
Output Power: 150 W  
Gain: 13 dB
- Low thermal resistance
- Ruggedness tested at rated output power
- Nitride passivated die for enhanced reliability

### Product Image



### MAXIMUM RATINGS

| Rating   | Symbol    | Value           | Unit                         |
|--|-----------|-----------------|------------------------------|
| Drain–Source Voltage   | $V_{DSS}$ | 65              | Vdc                          |
| Drain–Gate Voltage   | $V_{DGO}$ | 65              | Vdc                          |
| Gate–Source Voltage  | $V_{GS}$  | $\pm 40$        | Vdc                          |
| Drain Current — Continuous   | $I_D$     | 16              | Adc                          |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$     | 300<br>1.71     | Watts<br>W/ $^\circ\text{C}$ |
| Storage Temperature Range  | $T_{stg}$ | $-65$ to $+150$ | $^\circ\text{C}$             |
| Operating Junction Temperature   | $T_J$     | 200             | $^\circ\text{C}$             |

### THERMAL CHARACTERISTICS

| Characteristic                       | Symbol          | Max | Unit               |
|--------------------------------------|-----------------|-----|--------------------|
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 0.6 | $^\circ\text{C/W}$ |

**NOTE — CAUTION** — MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.

## RF Power FET 150W, to 175MHz, 28V

Rev. V1

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

#### OFF CHARACTERISTICS (1)

|   |                      |    |   |     |      |
|---|----------------------|----|---|-----|------|
| Drain–Source Breakdown Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 100 mA) | V <sub>(BR)DSS</sub> | 65 | — | —   | Vdc  |
| Zero Gate Voltage Drain Current (V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0) | I <sub>DSS</sub>     | —  | — | 5.0 | mAdc |
| Gate–Body Leakage Current (V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0)       | I <sub>GSS</sub>     | —  | — | 1.0 | μAdc |

#### ON CHARACTERISTICS (1)

|   |                     |     |     |     |      |
|---|---------------------|-----|-----|-----|------|
| Gate Threshold Voltage (V <sub>DS</sub> = 10 V, I <sub>D</sub> = 100 mA)  | V <sub>GS(th)</sub> | 1.0 | 3.0 | 5.0 | Vdc  |
| Drain–Source On–Voltage (V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A)   | V <sub>DS(on)</sub> | 0.1 | 0.9 | 1.5 | Vdc  |
| Forward Transconductance (V <sub>DS</sub> = 10 V, I <sub>D</sub> = 5.0 A) | g <sub>fs</sub>     | 5.0 | 7.0 | —   | mhos |

#### DYNAMIC CHARACTERISTICS (1)

|   |                  |   |     |   |    |
|---|------------------|---|-----|---|----|
| Input Capacitance (V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0, f = 1.0 MHz)            | C <sub>iss</sub> | — | 350 | — | pF |
| Output Capacitance (V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0, f = 1.0 MHz)           | C <sub>oss</sub> | — | 420 | — | pF |
| Reverse Transfer Capacitance (V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0, f = 1.0 MHz) | C <sub>rss</sub> | — | 35  | — | pF |

#### FUNCTIONAL TESTS

|  |   |                                |            |          |    |
|--|---|--------------------------------|------------|----------|----|
| Common Source Amplifier Power Gain, f = 30; 30.001 MHz<br>(V <sub>DD</sub> = 28 V, P <sub>out</sub> = 150 W (PEP), I <sub>DQ</sub> = 250 mA) f = 175 MHz     | G <sub>ps</sub>                             | 16<br>—                        | 20<br>10   | —<br>—   | dB |
| Drain Efficiency<br>(V <sub>DD</sub> = 28 V, P <sub>out</sub> = 150 W (PEP), f = 30; 30.001 MHz,<br>I <sub>DQ</sub> = 250 mA, I <sub>D</sub> (Max) = 5.95 A) | η   | 40                             | 45         | —        | %  |
| Intermodulation Distortion (1)<br>(V <sub>DD</sub> = 28 V, P <sub>out</sub> = 150 W (PEP), f = 30 MHz,<br>f2 = 30.001 MHz, I <sub>DQ</sub> = 250 mA)         | IMD <sub>(d3)</sub><br>IMD <sub>(d11)</sub> | —<br>—                         | –30<br>–60 | –28<br>— | dB |
| Load Mismatch<br>(V <sub>DD</sub> = 28 V, P <sub>out</sub> = 150 W (PEP), f1 = 30; 30.001 MHz,<br>I <sub>DQ</sub> = 250 mA, VSWR 30:1 at all Phase Angles)   | ψ   | No Degradation in Output Power |            |          |    |

#### CLASS A PERFORMANCE

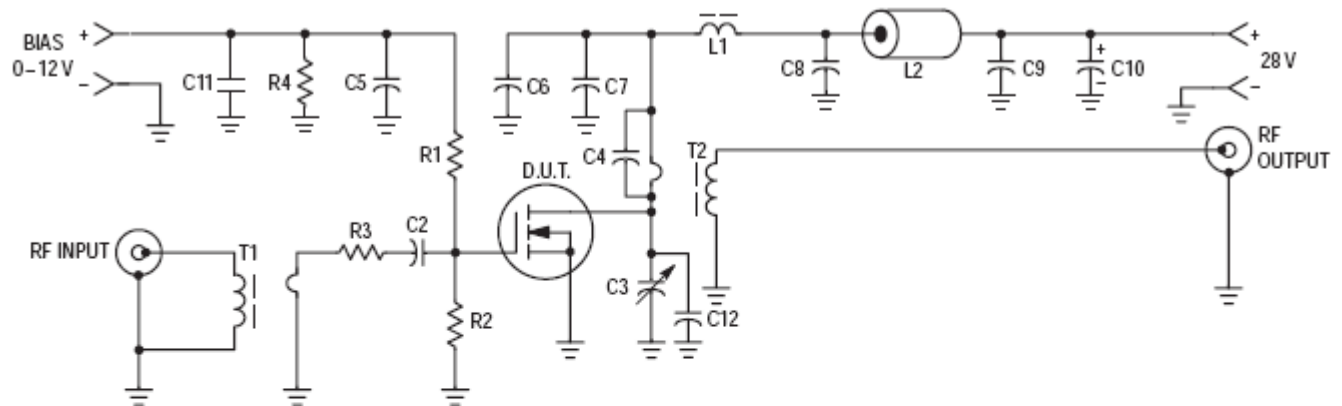
|  |  |             |                  |             |    |
|--|--|-------------|------------------|-------------|----|
| Intermodulation Distortion (1) and Power Gain<br>(V <sub>DD</sub> = 28 V, P <sub>out</sub> = 50 W (PEP), f1 = 30 MHz,<br>f2 = 30.001 MHz, I <sub>DQ</sub> = 4.0 A) | G <sub>PS</sub><br>IMD <sub>(d3)</sub><br>IMD <sub>(d9–13)</sub> | —<br>—<br>— | 23<br>–50<br>–75 | —<br>—<br>— | dB |
|--|--|-------------|------------------|-------------|----|

#### NOTE:

1. To MIL–STD–1311 Version A, Test Method 2204B, Two Tone, Reference Each Tone.

## RF Power FET 150W, to 175MHz, 28V

Rev. V1



C2, C5, C6, C7, C8, C9 — 0.1  $\mu$ F Ceramic Chip or Monolithic with Short Leads  
 C3 — Arco 469  
 C4 — 820 pF Unencapsulated Mica or Dipped Mica with Short Leads  
 C10 — 10  $\mu$ F/100 V Electrolytic  
 C11 — 1  $\mu$ F, 50 V, Tantalum  
 C12 — 330 pF, Dipped Mica (Short leads)

L1 — VK200/4B Ferrite Choke or Equivalent, 3.0  $\mu$ H  
 L2 — Ferrite Bead(s), 2.0  $\mu$ H  
 R1, R2 — 51  $\Omega$ /1.0 W Carbon  
 R3 — 1.0  $\Omega$ /1.0 W Carbon or Parallel Two 2  $\Omega$ , 1/2 W Resistors  
 R4 — 1 k $\Omega$ /1/2 W Carbon  
 T1 — 16:1 Broadband Transformer  
 T2 — 1:25 Broadband Transformer  
 Board Material — 0.062" Fiberglass (G10), 1 oz. Copper Clad, 2 Sides,  $\epsilon_r = 5$

Figure 1. 30 MHz Test Circuit (Class AB)

### TYPICAL CHARACTERISTICS

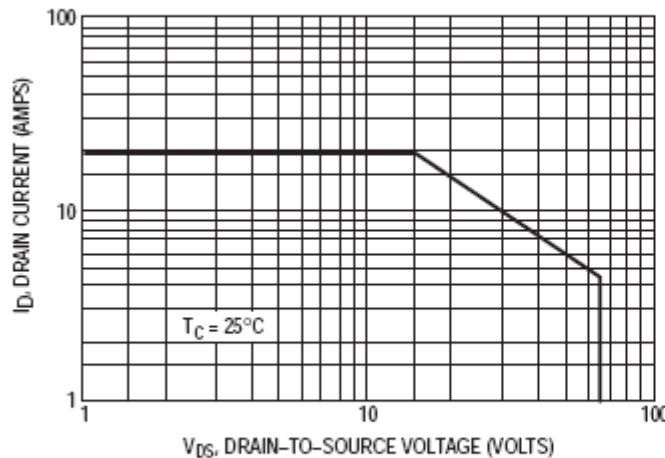


Figure 2. DC Safe Operating Area

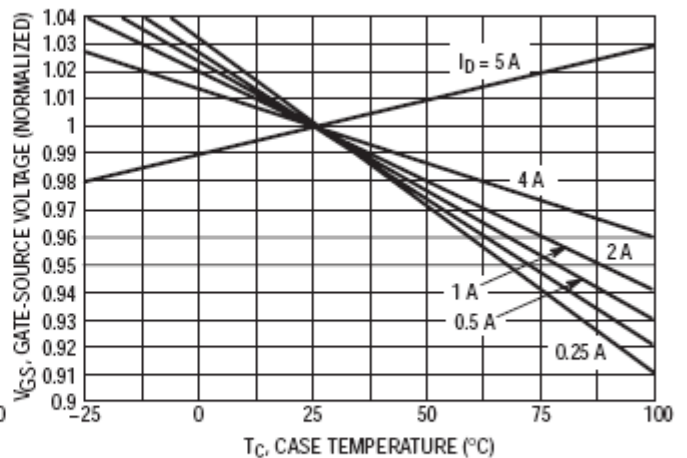


Figure 3. Gate-Source Voltage versus Case Temperature

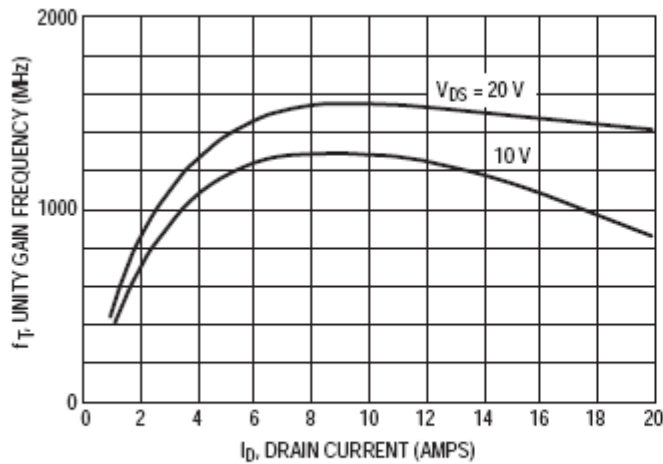


Figure 4. Common Source Unity Gain Frequency versus Drain Current

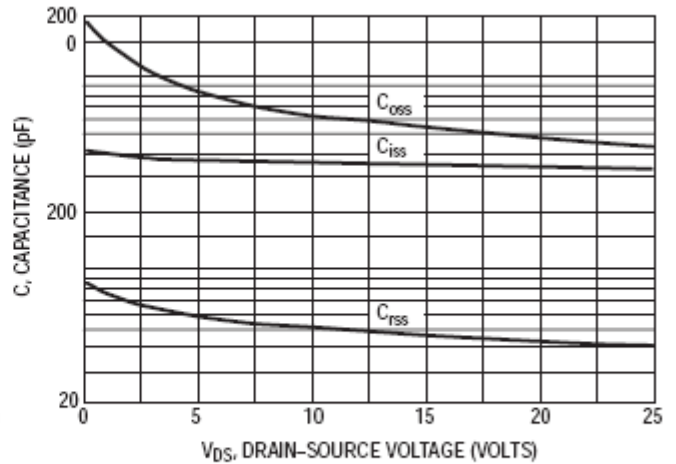


Figure 5. Capacitance versus Drain-Source Voltage

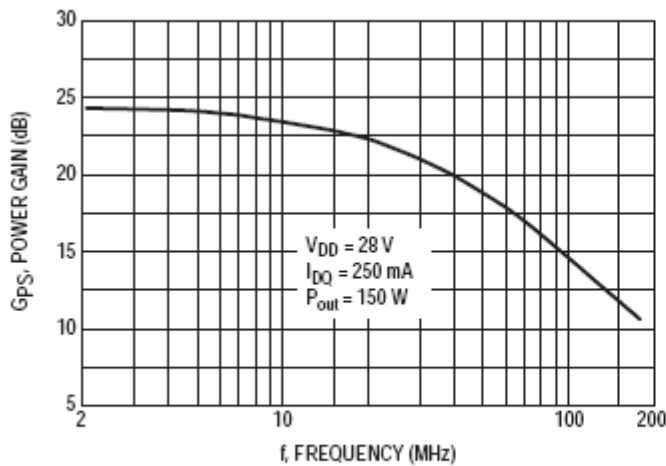


Figure 6. Power Gain versus Frequency

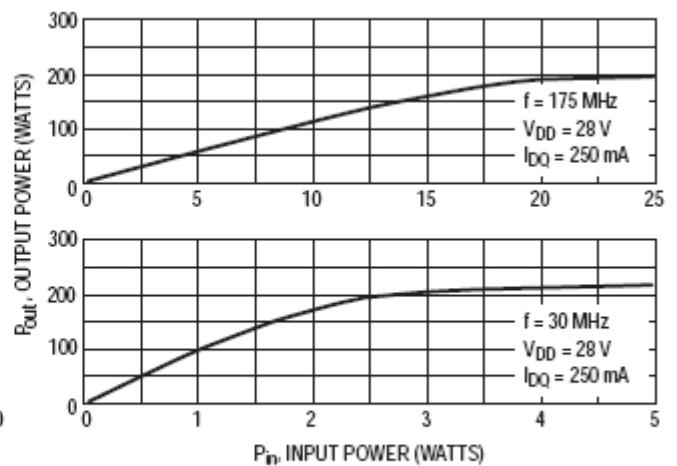


Figure 7. Output Power versus Input Power

## TYPICAL CHARACTERISTICS

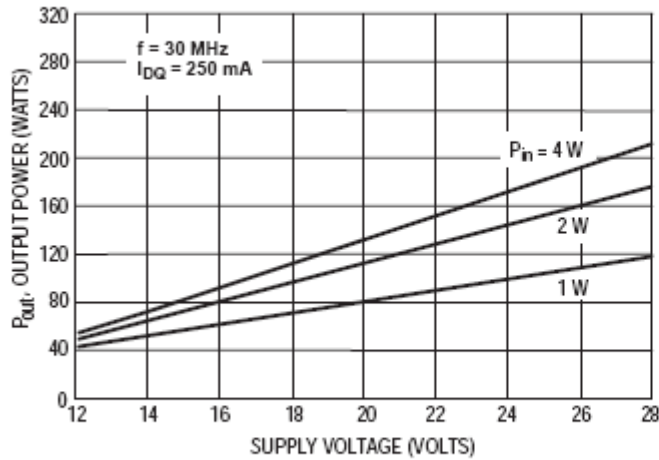


Figure 8. Output Power versus Supply Voltage

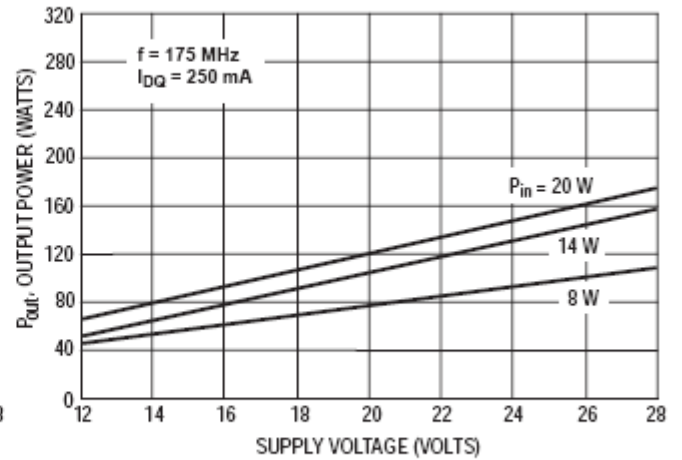


Figure 9. Output Power versus Supply Voltage

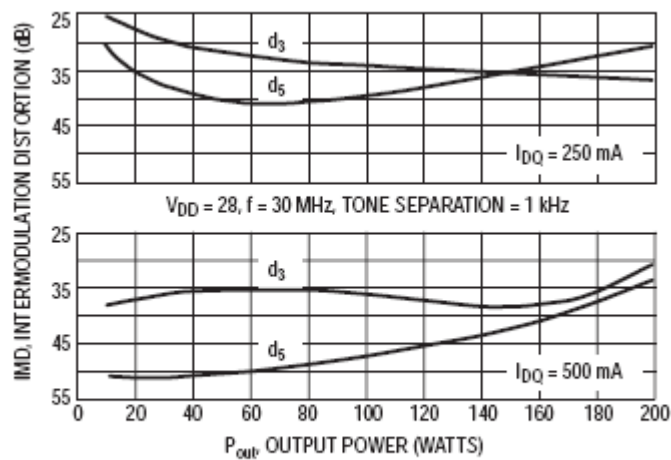


Figure 10. IMD versus  $P_{out}$  (PEP)

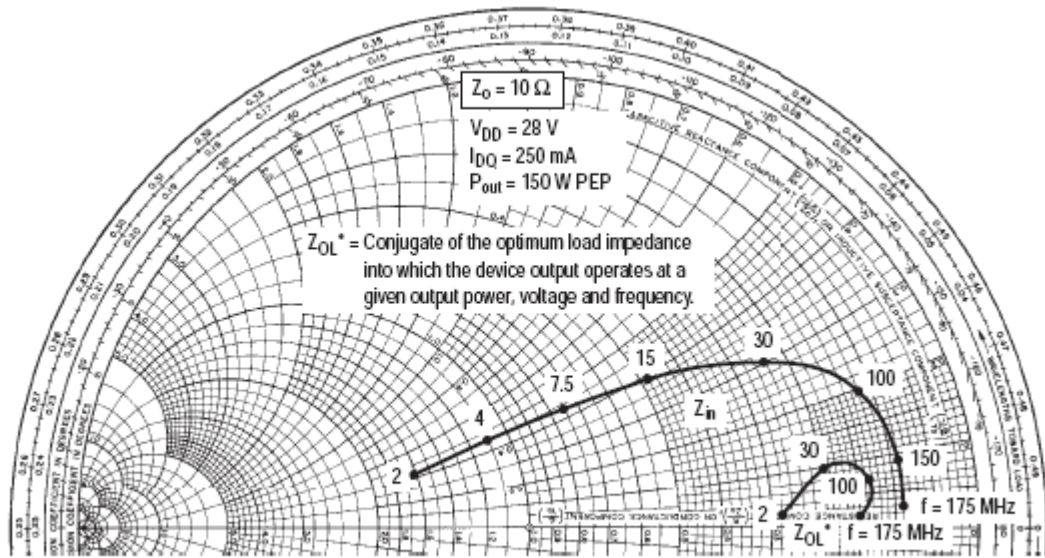
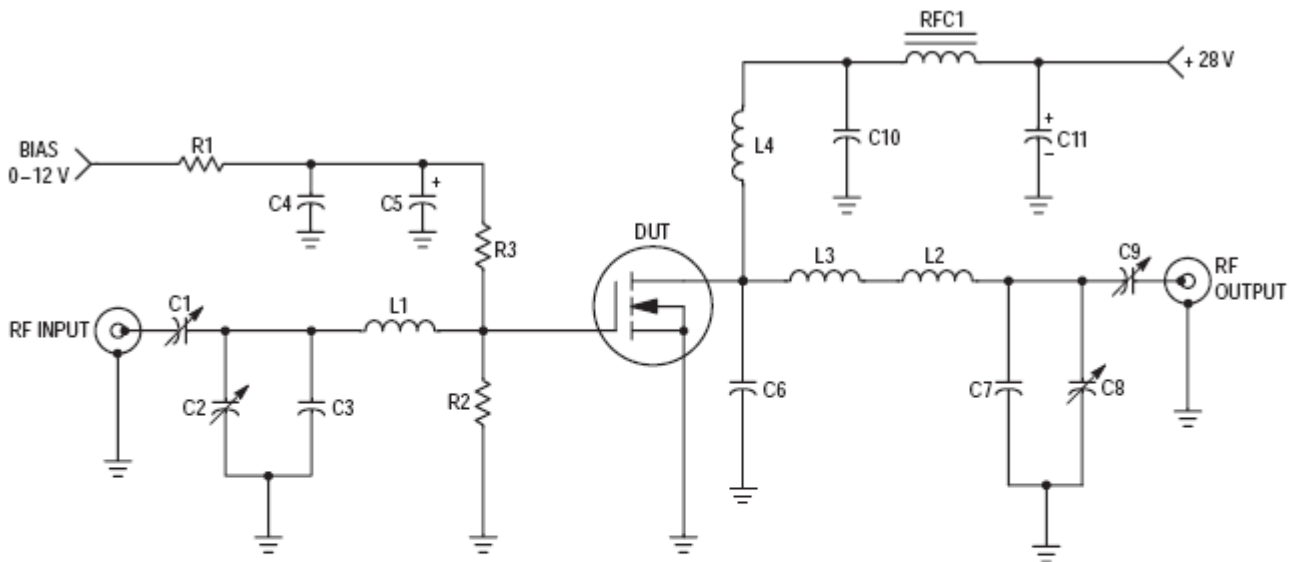


Figure 11. Input and Output Impedances



- C1, C2, C8 — Arco 463 or equivalent
- C3 — 25 pF, Unelco
- C4 — 0.1  $\mu$ F, Ceramic
- C5 — 1.0  $\mu$ F, 15 WV Tantalum
- C6 — 25 pF, Unelco J101
- C7 — 25 pF, Unelco J101
- C9 — Arco 262 or equivalent
- C10 — 0.05  $\mu$ F, Ceramic
- C11 — 15  $\mu$ F, 35 WV Electrolytic

- L1 — 3/4", #18 AWG into Hairpin
- L2 — Printed Line, 0.200" x 0.500"
- L3 — 7/8", #16 AWG into Hairpin
- L4 — 2 Turns, #16 AWG, 5/16 ID
- RFC1 — 5.6  $\mu$ H, Molded Choke
- RFC2 — VK200-4B
- R1 — 150  $\Omega$ , 1.0 W Carbon
- R2 — 10 k $\Omega$ , 1/2 W Carbon
- R3 — 120  $\Omega$ , 1/2 W Carbon

Figure 12. 175 MHz Test Circuit (Class AB)

## RF Power FET 150W, to 175MHz, 28V

Rev. V1

Table 1. Common Source S-Parameters ( $V_{DS} = 24\text{ V}$ ,  $I_D = 5\text{ A}$ )

| f<br>MHz | S <sub>11</sub> |      | S <sub>21</sub> |    | S <sub>12</sub> |     | S <sub>22</sub> |      |
|----------|-----------------|------|-----------------|----|-----------------|-----|-----------------|------|
|          | S <sub>11</sub> | φ    | S <sub>21</sub> | φ  | S <sub>12</sub> | φ   | S <sub>22</sub> | φ    |
| 30       | 0.916           | -177 | 4.23            | 83 | 0.008           | 32  | 0.876           | -177 |
| 40       | 0.919           | -178 | 3.23            | 76 | 0.009           | 39  | 0.885           | 178  |
| 50       | 0.922           | -178 | 2.55            | 72 | 0.010           | 45  | 0.914           | -180 |
| 60       | 0.923           | -179 | 2.14            | 68 | 0.010           | 46  | 0.893           | 179  |
| 70       | 0.927           | -179 | 1.77            | 63 | 0.011           | 48  | 0.878           | 179  |
| 80       | 0.929           | -179 | 1.48            | 61 | 0.013           | 53  | 0.864           | 180  |
| 90       | 0.931           | -180 | 1.28            | 60 | 0.015           | 61  | 0.850           | 180  |
| 100      | 0.934           | -180 | 1.15            | 55 | 0.016           | 66  | 0.893           | 178  |
| 110      | 0.935           | 180  | 1.05            | 53 | 0.016           | 69  | 0.913           | 177  |
| 120      | 0.939           | 180  | 0.91            | 51 | 0.017           | 69  | 0.930           | 180  |
| 130      | 0.941           | 179  | 0.82            | 48 | 0.019           | 67  | 0.916           | -180 |
| 140      | 0.943           | 179  | 0.76            | 46 | 0.022           | 68  | 0.926           | 179  |
| 150      | 0.946           | 179  | 0.67            | 42 | 0.024           | 70  | 0.940           | 177  |
| 160      | 0.946           | 179  | 0.63            | 40 | 0.025           | 73  | 0.915           | 178  |
| 170      | 0.948           | 178  | 0.57            | 39 | 0.024           | 78  | 0.891           | 178  |
| 180      | 0.949           | 178  | 0.52            | 37 | 0.026           | 75  | 0.906           | 178  |
| 190      | 0.950           | 178  | 0.49            | 37 | 0.028           | 74  | 0.899           | 176  |
| 200      | 0.950           | 177  | 0.45            | 35 | 0.030           | 78  | 0.915           | 176  |
| 210      | 0.938           | 177  | 0.43            | 31 | 0.043           | 108 | 0.966           | 174  |
| 220      | 0.958           | 178  | 0.39            | 33 | 0.029           | 61  | 0.972           | 175  |
| 230      | 0.961           | 177  | 0.36            | 27 | 0.038           | 77  | 1.033           | 174  |
| 240      | 0.960           | 177  | 0.36            | 28 | 0.036           | 76  | 0.943           | 174  |
| 250      | 0.961           | 176  | 0.32            | 30 | 0.038           | 77  | 0.912           | 175  |
| 260      | 0.962           | 176  | 0.30            | 31 | 0.040           | 76  | 0.918           | 174  |
| 270      | 0.961           | 176  | 0.27            | 30 | 0.044           | 77  | 0.933           | 171  |
| 280      | 0.963           | 176  | 0.26            | 30 | 0.045           | 79  | 0.943           | 172  |
| 290      | 0.964           | 175  | 0.25            | 25 | 0.045           | 78  | 0.940           | 172  |
| 300      | 0.965           | 175  | 0.26            | 27 | 0.047           | 77  | 0.930           | 172  |
| 310      | 0.966           | 175  | 0.25            | 27 | 0.051           | 78  | 0.977           | 172  |
| 320      | 0.964           | 175  | 0.24            | 26 | 0.053           | 75  | 0.947           | 171  |
| 330      | 0.966           | 174  | 0.22            | 21 | 0.056           | 75  | 0.946           | 170  |
| 340      | 0.967           | 174  | 0.23            | 26 | 0.056           | 75  | 0.944           | 170  |
| 350      | 0.967           | 174  | 0.22            | 24 | 0.058           | 78  | 0.946           | 171  |
| 360      | 0.965           | 174  | 0.21            | 28 | 0.062           | 74  | 0.956           | 171  |
| 370      | 0.966           | 174  | 0.20            | 28 | 0.048           | 61  | 0.968           | 170  |
| 380      | 0.968           | 173  | 0.20            | 27 | 0.053           | 74  | 0.931           | 168  |
| 390      | 0.970           | 173  | 0.18            | 31 | 0.063           | 74  | 0.962           | 168  |
| 400      | 0.970           | 173  | 0.17            | 26 | 0.071           | 79  | 0.965           | 172  |
| 410      | 0.970           | 172  | 0.17            | 29 | 0.076           | 78  | 0.982           | 169  |
| 420      | 0.971           | 172  | 0.17            | 30 | 0.076           | 76  | 0.956           | 167  |
| 430      | 0.970           | 172  | 0.15            | 29 | 0.070           | 76  | 0.912           | 165  |
| 440      | 0.970           | 171  | 0.13            | 32 | 0.074           | 76  | 0.933           | 167  |

Table 1. Common Source S-Parameters ( $V_{DS} = 24\text{ V}$ ,  $I_D = 5\text{ A}$ ) continued

| f<br>MHz | S <sub>11</sub> |     | S <sub>21</sub> |    | S <sub>12</sub> |    | S <sub>22</sub> |     |
|----------|-----------------|-----|-----------------|----|-----------------|----|-----------------|-----|
|          | S <sub>11</sub> | φ   | S <sub>21</sub> | φ  | S <sub>12</sub> | φ  | S <sub>22</sub> | φ   |
| 450      | 0.970           | 171 | 0.15            | 31 | 0.081           | 76 | 0.967           | 167 |
| 460      | 0.970           | 171 | 0.15            | 32 | 0.090           | 73 | 0.982           | 164 |
| 470      | 0.969           | 170 | 0.15            | 30 | 0.095           | 77 | 0.945           | 165 |
| 480      | 0.964           | 170 | 0.16            | 34 | 0.099           | 80 | 0.956           | 165 |
| 490      | 0.960           | 170 | 0.15            | 31 | 0.107           | 75 | 0.947           | 163 |
| 500      | 0.959           | 170 | 0.15            | 23 | 0.103           | 68 | 0.962           | 163 |

Table 2. Common Source S-Parameters ( $V_{DS} = 28\text{ V}$ ,  $I_D = 5\text{ A}$ )

| f<br>MHz | S <sub>11</sub> |      | S <sub>21</sub> |    | S <sub>12</sub> |    | S <sub>22</sub> |      |
|----------|-----------------|------|-----------------|----|-----------------|----|-----------------|------|
|          | S <sub>11</sub> | φ    | S <sub>21</sub> | φ  | S <sub>12</sub> | φ  | S <sub>22</sub> | φ    |
| 30       | 0.914           | -177 | 4.60            | 82 | 0.007           | 25 | 0.874           | -176 |
| 40       | 0.915           | -178 | 3.51            | 76 | 0.008           | 26 | 0.879           | -179 |
| 50       | 0.918           | -178 | 2.76            | 71 | 0.009           | 34 | 0.888           | -179 |
| 60       | 0.920           | -178 | 2.32            | 67 | 0.010           | 45 | 0.881           | 179  |
| 70       | 0.924           | -179 | 1.92            | 62 | 0.010           | 56 | 0.887           | 179  |
| 80       | 0.927           | -179 | 1.61            | 60 | 0.009           | 62 | 0.899           | -179 |
| 90       | 0.930           | -179 | 1.39            | 58 | 0.010           | 61 | 0.874           | -177 |
| 100      | 0.933           | -180 | 1.23            | 53 | 0.012           | 57 | 0.875           | -179 |
| 110      | 0.934           | -180 | 1.13            | 51 | 0.015           | 63 | 0.884           | 179  |
| 120      | 0.938           | 180  | 0.98            | 49 | 0.017           | 73 | 0.926           | 179  |
| 130      | 0.940           | 180  | 0.88            | 46 | 0.018           | 81 | 0.959           | -179 |
| 140      | 0.942           | 179  | 0.81            | 44 | 0.018           | 82 | 0.966           | -179 |
| 150      | 0.945           | 179  | 0.71            | 40 | 0.018           | 77 | 0.961           | -179 |
| 160      | 0.946           | 179  | 0.67            | 38 | 0.021           | 73 | 0.910           | -179 |
| 170      | 0.948           | 178  | 0.61            | 37 | 0.023           | 77 | 0.871           | 179  |
| 180      | 0.950           | 178  | 0.54            | 35 | 0.026           | 78 | 0.912           | 178  |
| 190      | 0.950           | 178  | 0.52            | 34 | 0.029           | 76 | 0.959           | 177  |
| 200      | 0.952           | 178  | 0.47            | 33 | 0.034           | 64 | 0.971           | 178  |
| 210      | 0.949           | 177  | 0.46            | 28 | 0.067           | 17 | 1.023           | -178 |
| 220      | 0.953           | 178  | 0.41            | 31 | 0.019           | 94 | 0.954           | 177  |
| 230      | 0.959           | 177  | 0.38            | 26 | 0.037           | 76 | 1.014           | 174  |
| 240      | 0.960           | 177  | 0.37            | 25 | 0.040           | 79 | 0.943           | 174  |



**RF Power FET**  
**150W, to 175MHz, 28V**

Rev. V1

**Table 2. Common Source S-Parameters ( $V_{DS}= 28V$ ,  $I_D = 5A$ ) - Con't.**

| f<br>MHz | S <sub>11</sub> |     | S <sub>21</sub> |    | S <sub>12</sub> |    | S <sub>22</sub> |     |
|----------|-----------------|-----|-----------------|----|-----------------|----|-----------------|-----|
|          | S <sub>11</sub> | φ   | S <sub>21</sub> | φ  | S <sub>12</sub> | φ  | S <sub>22</sub> | φ   |
| 250      | 0.961           | 177 | 0.33            | 27 | 0.042           | 84 | 0.972           | 175 |
| 260      | 0.962           | 176 | 0.30            | 27 | 0.041           | 86 | 0.969           | 176 |
| 270      | 0.961           | 176 | 0.29            | 27 | 0.041           | 83 | 0.951           | 175 |
| 280      | 0.963           | 176 | 0.27            | 27 | 0.042           | 80 | 0.929           | 174 |
| 290      | 0.964           | 175 | 0.26            | 23 | 0.045           | 79 | 0.930           | 172 |
| 300      | 0.965           | 175 | 0.27            | 25 | 0.051           | 81 | 0.963           | 171 |
| 310      | 0.966           | 175 | 0.26            | 24 | 0.052           | 83 | 1.012           | 173 |
| 320      | 0.965           | 175 | 0.25            | 23 | 0.053           | 81 | 0.984           | 171 |
| 330      | 0.966           | 174 | 0.23            | 19 | 0.055           | 78 | 0.955           | 172 |
| 340      | 0.967           | 174 | 0.24            | 25 | 0.054           | 76 | 0.929           | 171 |
| 350      | 0.967           | 174 | 0.22            | 22 | 0.057           | 79 | 0.917           | 170 |
| 360      | 0.967           | 174 | 0.21            | 26 | 0.060           | 91 | 0.978           | 169 |
| 370      | 0.967           | 174 | 0.20            | 26 | 0.084           | 89 | 1.030           | 167 |
| 380      | 0.969           | 173 | 0.20            | 23 | 0.081           | 82 | 0.994           | 170 |
| 390      | 0.970           | 173 | 0.19            | 29 | 0.072           | 80 | 0.963           | 170 |
| 400      | 0.970           | 173 | 0.17            | 25 | 0.069           | 80 | 0.951           | 172 |
| 410      | 0.970           | 172 | 0.17            | 27 | 0.072           | 71 | 0.985           | 167 |
| 420      | 0.972           | 172 | 0.16            | 28 | 0.078           | 68 | 0.970           | 165 |
| 430      | 0.971           | 172 | 0.15            | 27 | 0.084           | 70 | 0.953           | 165 |
| 440      | 0.971           | 171 | 0.13            | 29 | 0.086           | 74 | 0.949           | 168 |
| 450      | 0.971           | 171 | 0.15            | 29 | 0.087           | 79 | 0.962           | 167 |
| 460      | 0.970           | 171 | 0.15            | 32 | 0.081           | 72 | 0.976           | 164 |
| 470      | 0.969           | 170 | 0.15            | 29 | 0.079           | 65 | 0.969           | 164 |
| 480      | 0.964           | 170 | 0.16            | 32 | 0.081           | 57 | 0.972           | 165 |
| 490      | 0.959           | 170 | 0.15            | 29 | 0.081           | 54 | 0.976           | 165 |
| 500      | 0.958           | 170 | 0.15            | 21 | 0.086           | 58 | 0.953           | 167 |

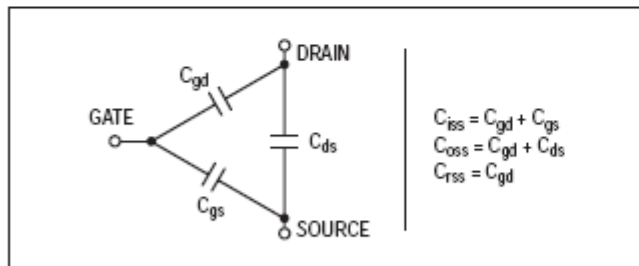
## RF POWER MOSFET CONSIDERATIONS

## MOSFET CAPACITANCES

The physical structure of a MOSFET results in capacitors between the terminals. The metal oxide gate structure determines the capacitors from gate-to-drain ( $C_{gd}$ ), and gate-to-source ( $C_{gs}$ ). The PN junction formed during the fabrication of the RF MOSFET results in a junction capacitance from drain-to-source ( $C_{ds}$ ).

These capacitances are characterized as input ( $C_{iss}$ ), output ( $C_{oss}$ ) and reverse transfer ( $C_{rss}$ ) capacitances on data sheets. The relationships between the inter-terminal capacitances and those given on data sheets are shown below. The  $C_{iss}$  can be specified in two ways:

1. Drain shorted to source and positive voltage at the gate.
2. Positive voltage of the drain in respect to source and zero volts at the gate. In the latter case the numbers are lower. However, neither method represents the actual operating conditions in RF applications.



## LINEARITY AND GAIN CHARACTERISTICS

In addition to the typical IMD and power gain data presented, Figure 5 may give the designer additional information on the capabilities of this device. The graph represents the small signal unity current gain frequency at a given drain current level. This is equivalent to  $f_T$  for bipolar transistors.

Since this test is performed at a fast sweep speed, heating of the device does not occur. Thus, in normal use, the higher temperatures may degrade these characteristics to some extent.

## DRAIN CHARACTERISTICS

One figure of merit for a FET is its static resistance in the full-on condition. This on-resistance,  $V_{DS(on)}$ , occurs in the linear region of the output characteristic and is specified under specific test conditions for gate-source voltage and drain current. For MOSFETs,  $V_{DS(on)}$  has a positive temperature coefficient and constitutes an important design consideration at high temperatures, because it contributes to the power dissipation within the device.

## GATE CHARACTERISTICS

The gate of the RF MOSFET is a polysilicon material, and is electrically isolated from the source by a layer of oxide. The input resistance is very high — on the order of  $10^9$  ohms — resulting in a leakage current of a few nanoamperes.

Gate control is achieved by applying a positive voltage slightly in excess of the gate-to-source threshold voltage,  $V_{GS(th)}$ .

**Gate Voltage Rating** — Never exceed the gate voltage rating. Exceeding the rated  $V_{GS}$  can result in permanent damage to the oxide layer in the gate region.

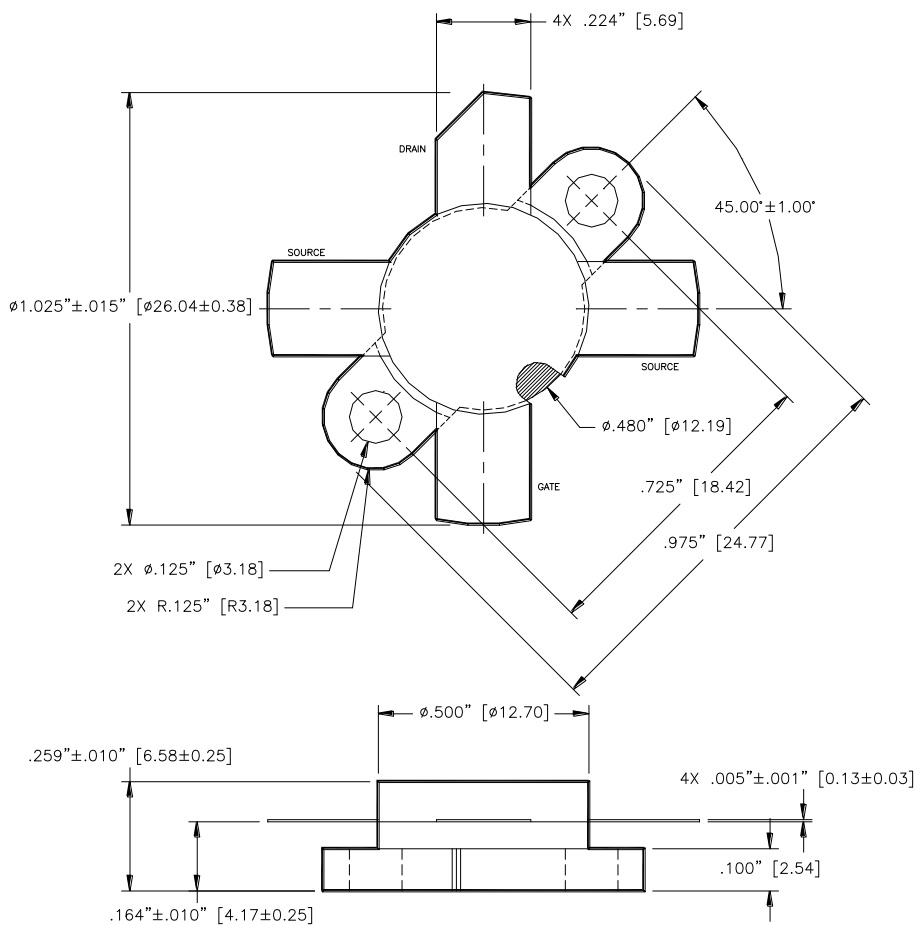
**Gate Termination** — The gates of these devices are essentially capacitors. Circuits that leave the gate open-circuited or floating should be avoided. These conditions can result in turn-on of the devices due to voltage build-up on the input capacitor due to leakage currents or pickup.

**Gate Protection** — These devices do not have an internal monolithic zener diode from gate-to-source. If gate protection is required, an external zener diode is recommended.

## EQUIVALENT TRANSISTOR PARAMETER TERMINOLOGY

|                     |               |
|---------------------|---------------|
| Collector .....     | Drain         |
| Emitter .....       | Source        |
| Base .....          | Gate          |
| $V_{(BR)CES}$ ..... | $V_{(BR)DSS}$ |
| $V_{CBO}$ .....     | $V_{DGO}$     |
| $I_C$ .....         | $I_D$         |
| $I_{CES}$ .....     | $I_{DSS}$     |
| $I_{EBO}$ .....     | $I_{GSS}$     |
| $V_{BE(on)}$ .....  | $V_{GS(th)}$  |
| $V_{CE(sat)}$ ..... | $V_{DS(on)}$  |
| $C_{ib}$ .....      | $C_{iss}$     |
| $C_{ob}$ .....      | $C_{oss}$     |
| $h_{fe}$ .....      | $g_{fs}$      |

$$R_{CE(sat)} = \frac{V_{CE(sat)}}{I_C} \quad \dots \quad r_{DS(on)} = \frac{V_{DS(on)}}{I_D}$$


Unless otherwise noted, tolerances are inches  $\pm 0.005$ " [millimeters  $\pm 0.13$ mm]

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